

ZX5T1951G
60V PNP MEDIUM POWER TRANSISTOR IN SOT223
Features and Benefits

- $BV_{CEO} > -60V$
- $I_C = -6A$ Continuous Collector Current
- Low Saturation Voltage ($-95mV$ max @ $-1A$)
- $R_{SAT} = 40m\Omega$ for a low equivalent On-Resistance
- h_{FE} specified up to $-10A$ for a high gain hold up
- **RoHS Compliant**
- **Halogen and Antimony Free. "Green" Device (Note 1)**
- **Qualified to AEC-Q101 Standards for High Reliability**

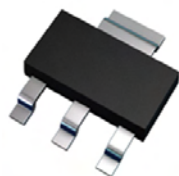
Applications

- Motor driving
- DC-DC modules
- Backlight inverters
- Actuator, relay, and solenoid drivers

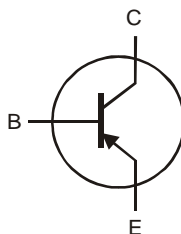
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper Leadframe
- Weight: 0.112 grams (Approximate)

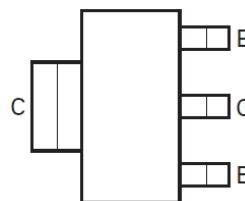
SOT223



Top View



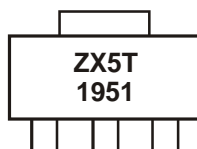
Device Symbol


 Top View
Pin-Out

Ordering Information (Note 2)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T1951GTA	ZX5T1951	7	12	1,000

- Notes:
1. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 2. For Packaging Details, go to our website at <http://www.diodes.com>.

Marking Information


ZX5T1951 = Product type Marking Code

Maximum Ratings @T_A = 25°C unless otherwise specified

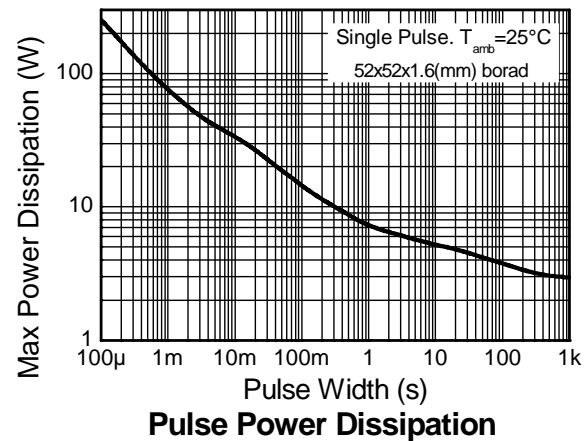
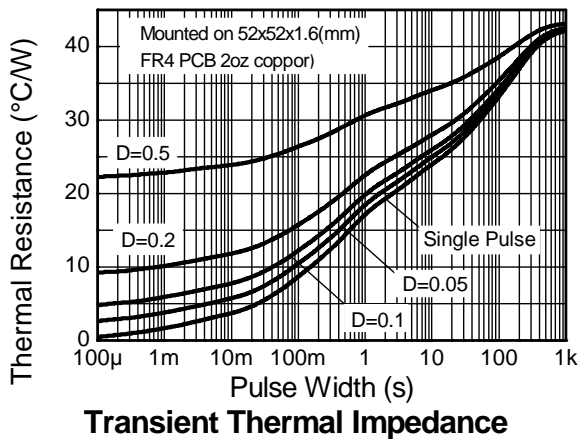
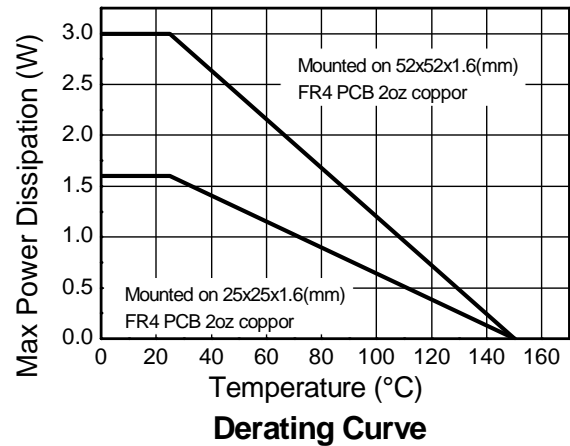
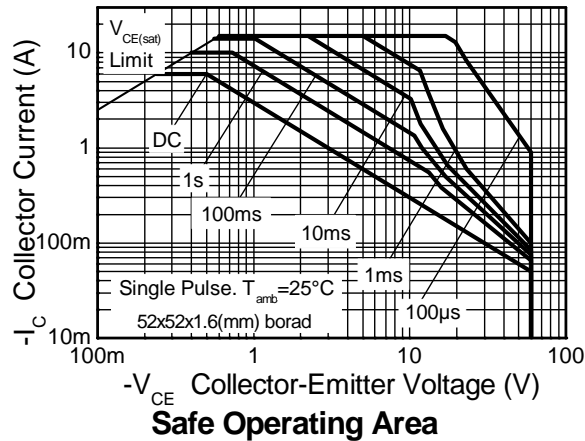
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-90	V
Collector-Emitter Voltage	V _{CES}	-90	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 3)	I _C	-6	A
Peak Pulse Current	I _{CM}	-15	A
Base Current	I _B	-1	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	3.0	W
Linear derating factor		24	
		1.6	
		12.8	
Thermal Resistance, Junction to Ambient	R _{θJA}	42	°C/W
	R _{θJA}	78	
Thermal Resistance Junction to Lead	R _{θJL}	12.3	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
3. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 4. Same as note (3), except the device is surface mounted on 25mm x 25mm with 1oz copper.
 5. Thermal resistance from junction to solder-point (at the end of the collector lead).

Thermal Characteristics

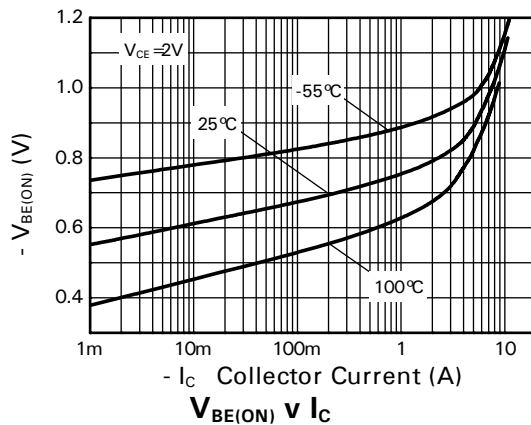
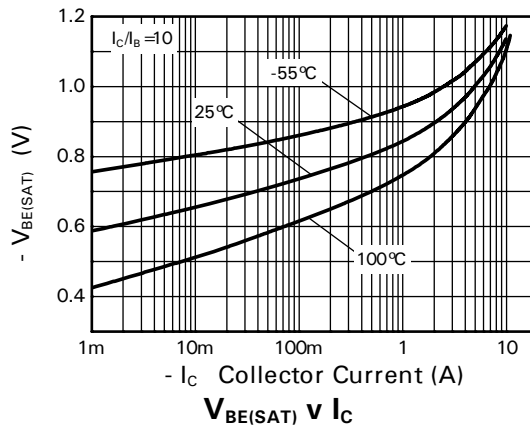
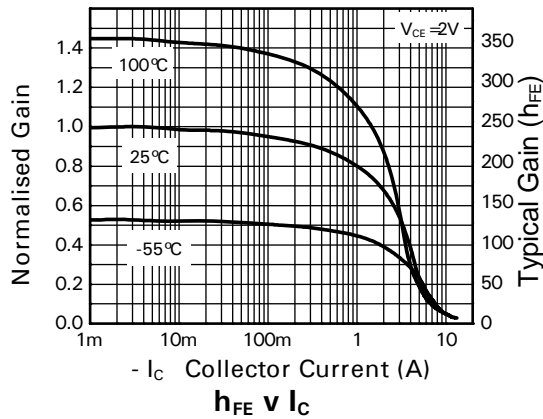
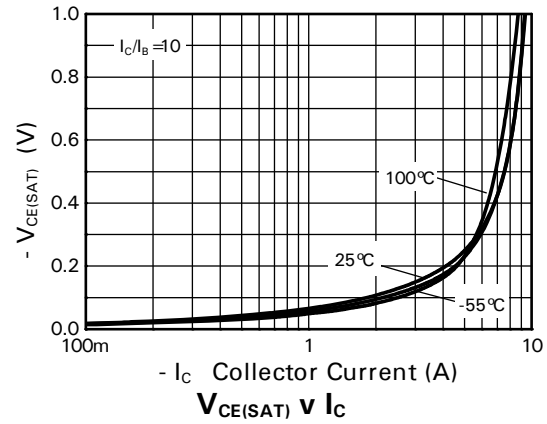
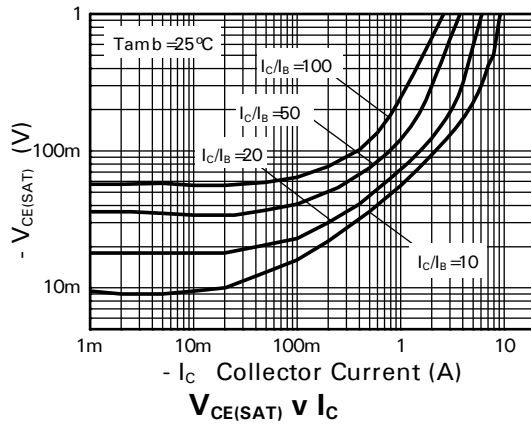


Electrical Characteristics @T_A = 25°C unless otherwise specified

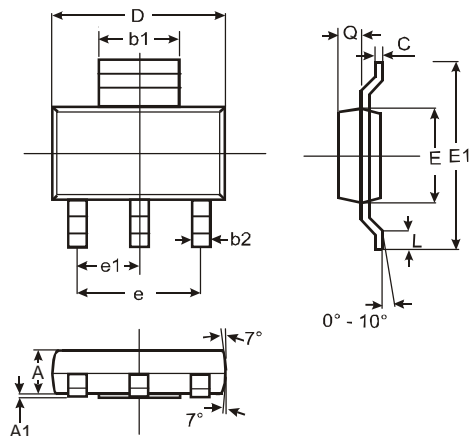
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-90	-120	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CES}	-90	-120	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	-60	-80	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	-	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}	-	<1	-50	nA	V _{CB} = -72V
Collector-Emitter Cutoff Current	I _{CES}	-	<1	-50	nA	V _{CB} = -72V
Emitter Cutoff Current	I _{EBO}	-	<1	-10	nA	V _{EB} = -6V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	100	240	-	-	I _C = -10mA, V _{CE} = -2V
		100	180	300		I _C = -2A, V _{CE} = -2V
		40	70	-		I _C = -5A, V _{CE} = -2V
		5	14	-		I _C = -10A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	-	-16	-30	mV	I _C = -100mA, I _B = -10mA
		-	-55	-95		I _C = -1A, I _B = -100mA
		-	-85	-130		I _C = -2A, I _B = -200mA
		-	-200	-260		I _C = -5A, I _B = -500mA
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	-1	-1.15	V	I _C = -5A, I _B = -500mA
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	-	-0.89	-1.0	V	I _C = -5A, V _{CE} = -2V
Output Capacitance (Note 6)	C _{obo}	-	33	70	pF	V _{CB} = -10V, f = 1MHz
Transition Frequency	f _T	-	120	-	MHz	V _{CE} = -10V, I _C = -100mA f = 50MHz
Switching Time	t _{on}	-	33	80	ns	V _{CC} = -10V, I _C = -2A I _{B1} = -I _{B2} = -200mA
	t _{off}	-	215	300		

Notes: 6. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics

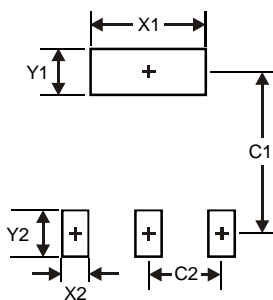


Package Outline Dimensions



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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